

Peak Emission Wavelength: 855nm

The 855nm Point Source Series is designed for applications requiring high accuracy and precision as well as parallel beam spectral emission. Custom package solutions and sorting are available.

FEATURES

- > Hermetically Sealed TO-18 Package
- > Emitting Window Diameter Φ 50 μ m
- > Gold Plated Flat Top Can
- > High Reliability / High Output Power

APPLICATIONS

- > Optical Scanning
- > Linear & Rotary Encoder
- > Edge Sensing / Optical Sensors
- > Fiber Optics / Optical Communications



Absolute Maximum Ratings (Ta=25°C)

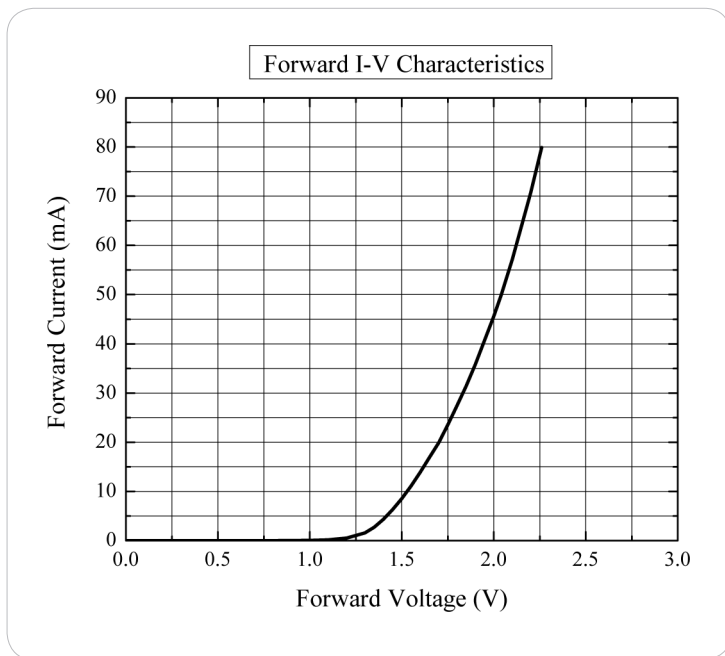
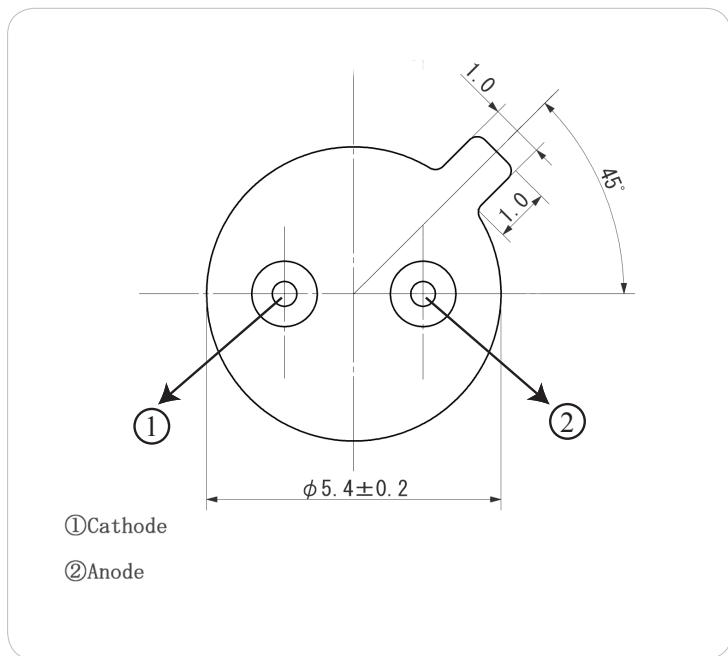
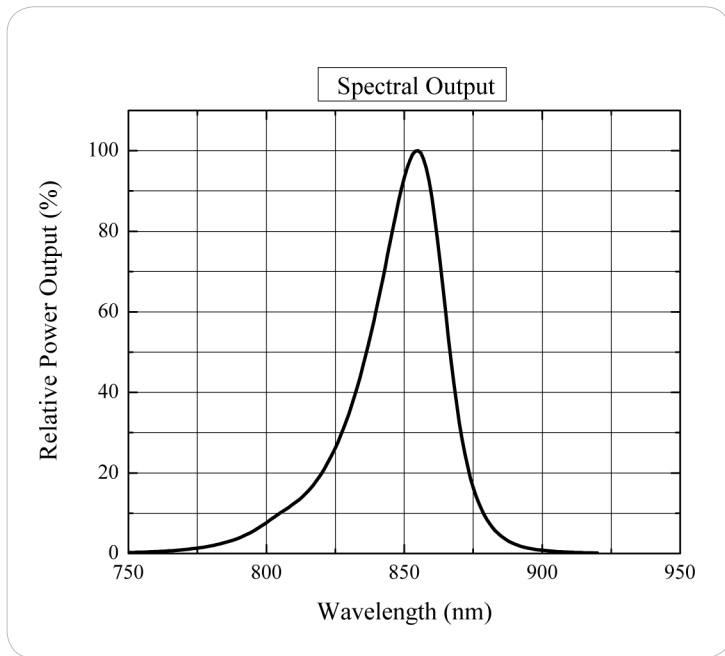
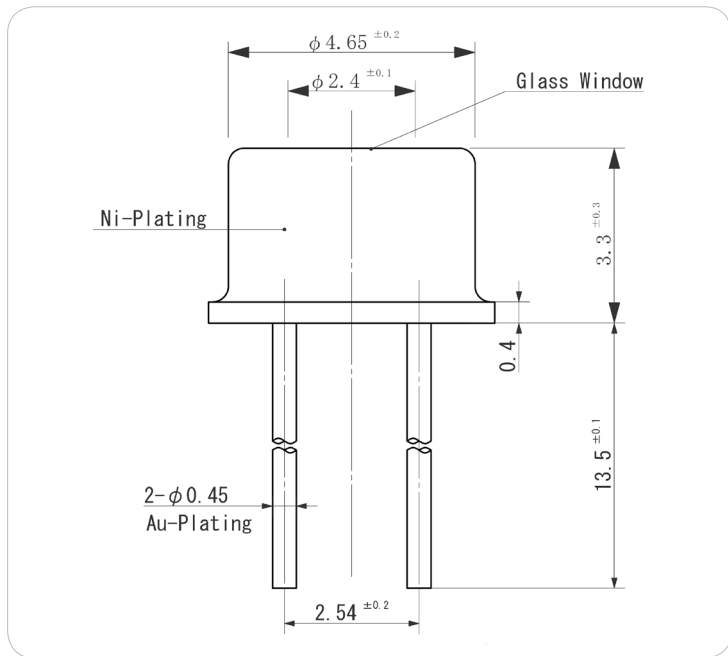


| ITEMS | SYMBOL | RATINGS | UNIT |
|------------------------------|--------|------------|------|
| Forward Current (DC) | IF | 80 | mA |
| Forward Current (Pulse)*1 | IFP | 0.4 | A |
| Reverse Voltage | VR | 5 | V |
| Power Dissipation | PD | 160 | mW |
| Operating Temperature Range | Topr | -30 ~ +100 | °C |
| Storage Temperature Range | Tstg | -40 ~ +125 | °C |
| Junction Temperature | Tj | 125 | °C |
| Lead Soldering Temperature*2 | Tls | 260 | °C |

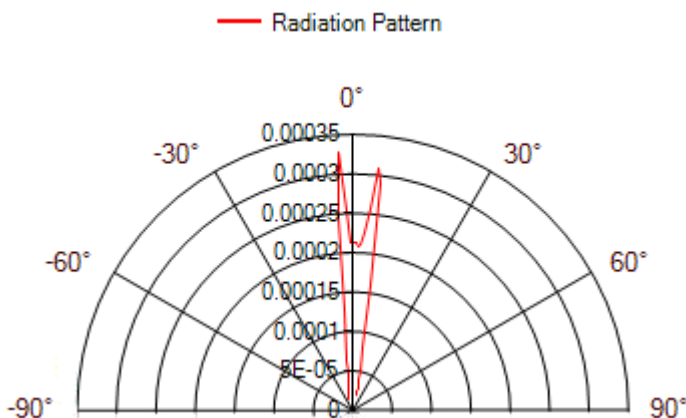
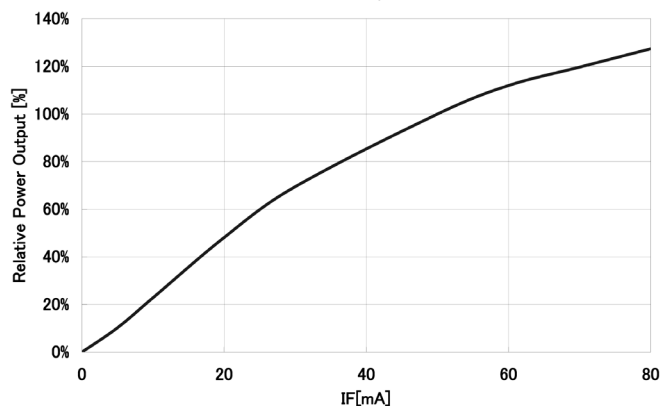
*1: Tw=10 μ sec, T=10msec. *2. Time 5sec Max, Position: Up to 3mm from the body.

Electrical & Optical Characteristics (Ta = 25°C)

| ITEMS | SYMBOL | CONDITIONS | MIN | TYP | MAX | UNIT |
|---------------------------|-----------------|------------|-----|---------|-----|---------|
| Power Output | Po | IF=50mA | -- | 1.7 | -- | mW |
| Forward Voltage | VF | IF=50mA | -- | 1.9 | 2.3 | V |
| Reverse Current | IR | VR=5V | -- | -- | 10 | μ A |
| Peak Wavelength | λ_p | IF=50mA | -- | 855 | -- | nm |
| Spectral Line Half Width | $\Delta\lambda$ | IF=50mA | -- | 30 | -- | nm |
| Half Intensity Beam Angle | Θ | IF=50mA | -- | ± 5 | -- | deg |



Unit: mm, Tolerance: ± 0.2



The information contained herein is subject to change without notice.

2013-01-28